IN THE CLAIMS:

In the pending claims, please amend claims 1, 5, 9, 13, 18 and 19 as follows.

1. (Currently Amended) A light-emitting device comprising:

a wiring formed on a first film;

~~a second film formed of the same layer as the wiring on the first film;~~

a ~~third~~ second film formed over the first film;

a contact hole provided in the ~~third~~ second film;

an electrode of a light-emitting element formed on the ~~third~~ second film;

a ~~fourth~~ third film covering an edge of the electrode of the light-emitting element,

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the ~~second film~~ wiring,

wherein the wiring is connected with the electrode of the light-emitting element [[in]] through the contact hole,

wherein ~~an opening of the fourth film provided in an overlap portion of the electrode of the light-emitting element and the second film~~ an entire exposed portion of the electrode of the light-emitting element in an opening of the third film overlaps with the wiring, and

wherein [[a]] the contact hole [[of]] in the ~~third~~ second film is overlapped with the ~~fourth~~ third film.

2. (Original) The light-emitting device according to claim 1, wherein a reflective film is included in the electrode of the light-emitting element.

3.-4. (Canceled)

5. (Currently Amended) A light-emitting device comprising:

a transistor including a semiconductor film, a gate insulating film, and a gate electrode;

a first film formed on the transistor;

a first contact hole provided in the first film;

a wiring formed on the first film;

~~a second film formed of the same layer as the wiring on the first film;~~

a ~~third~~ second film formed over the first film;

a second contact hole provided in the ~~third~~ second film;

an electrode of a light-emitting element formed on the ~~third~~ second film; and

a ~~fourth~~ third film covering an edge of the electrode of the light-emitting element,

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the ~~second film~~ wiring,

wherein ~~an opening of the fourth film is provided in an overlap portion of the electrode of the light-emitting element and the second film~~ an entire exposed portion of the electrode of the light-emitting element in an opening of the third film overlaps with the wiring, and

wherein [[a]] the first contact hole [[of]] in the first film and [[a]] the second contact hole [[of]] in the ~~third~~ second film are overlapped with the ~~fourth~~ third film.

6. (Original) The light-emitting device according to claim 5, wherein a reflective film is included in the electrode of the light-emitting element.

7.-8. (Canceled)

9. (Currently Amended) A light-emitting device comprising:

a semiconductor film;

a gate insulating film formed on the semiconductor film;

a gate electrode formed on the gate insulating film;

a first film formed on the gate electrode;

a first contact hole provided in the first film;

a wiring formed on the first film;

~~a second film formed of the same layer as the wiring on the first film;~~

a ~~third~~ second film formed over the first film;

a second contact hole provided in the ~~third~~ second film;

an electrode of a light-emitting element formed on the ~~third~~ second film; and

a ~~fourth~~ third film covering an edge of the electrode of the light-emitting element,

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the ~~second film~~ wiring,

wherein ~~an opening of the fourth film is provided in an overlap portion of the electrode of the light-emitting element and the second film~~ an entire exposed portion of the electrode of the light-emitting element in an opening of the third film overlaps with the wiring, and

wherein [[a]] the first contact hole [[of]] in the first film and [[a]] the second contact hole [[of]] in the ~~third~~ second film are overlapped with the ~~fourth~~ third film.

10. (Original) The light-emitting device according to claim 9, wherein a reflective film is provided in the electrode of the light-emitting element.

11.-12. (Canceled)

13. (Currently Amended) A light-emitting device comprising:

a conductive film formed on a first interlayer insulating film;

a second interlayer insulating film formed over the first interlayer insulating film;

an electrode of a light-emitting element formed on the second interlayer insulating film;

a contact hole provided in the second interlayer insulating film; and

a partition layer covering an edge of the electrode of the light-emitting

element,

wherein the electrode of the light-emitting element is electrically connected to the conductive film [[in]] through the contact hole,

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the conductive film,

wherein ~~an opening of the partition layer is provided in an overlap portion of the electrode of the light-emitting element and the conductive film~~ an entire exposed portion of the electrode of the light-emitting element in an opening of the partition layer overlaps with the conductive film, and

wherein the contact hole [[of]] in the second interlayer insulating film is overlapped with the partition layer.

14.-17. (Canceled)

18. (Currently Amended) A light-emitting device comprising:

a conductive film formed over a first insulating film;

a second insulating film formed over the first insulating film;

an electrode of a light-emitting element formed over the second insulating film;

a contact hole provided in the second insulating film; and

a partition layer covering an edge of the electrode of the light-emitting element,

wherein the electrode of the light-emitting element is electrically connected to the conductive film [[in]] through the contact hole,

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the conductive film,

wherein ~~an opening of the partition layer is provided in an overlap portion of the electrode of the light-emitting element and the conductive film~~ an entire exposed portion of the electrode of the light-emitting element in an opening of the

partition layer overlaps with the conductive film, and

wherein the contact hole [[of]] in the second insulating film is overlapped with the partition layer.

19. (Currently Amended) A light-emitting device comprising:

a conductive film formed over a first insulating film;

a second insulating film formed over the first insulating film;

an electrode of a light-emitting element formed over the second insulating film;

a partition layer covering an edge of the electrode of the light-emitting element; and

a color filter formed over the electrode of the light-emitting element,

wherein the electrode of the light-emitting element is electrically connected to the conductive film [[in]] through a contact hole in the second insulating film,

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the conductive film,

wherein ~~an opening of the partition layer is provided in an overlap portion of the electrode of the light-emitting element and the conductive film~~ an entire exposed portion of the electrode of the light-emitting element in an opening of the partition layer overlaps with the conductive film, and

wherein the color filter is overlapped with the overlap portion of the electrode of the light-emitting element and the conductive film.

20. (Previously Presented) The light-emitting device according to claim 1, wherein the light-emitting device is an active matrix display device.

21. (Previously Presented) The light-emitting device according to claim 13, wherein the light-emitting device is an active matrix display device.

22. (Previously Presented) The light-emitting device according to claim 18, wherein the light-emitting device is an active matrix display device.

23. (Previously Presented) The light-emitting device according to claim 19, wherein the light-emitting device is an active matrix display device.